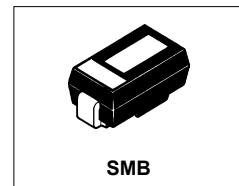


International
IR Rectifier

MBRS190TR
MBRS1100TR

SCHOTTKY RECTIFIER

1 Amp



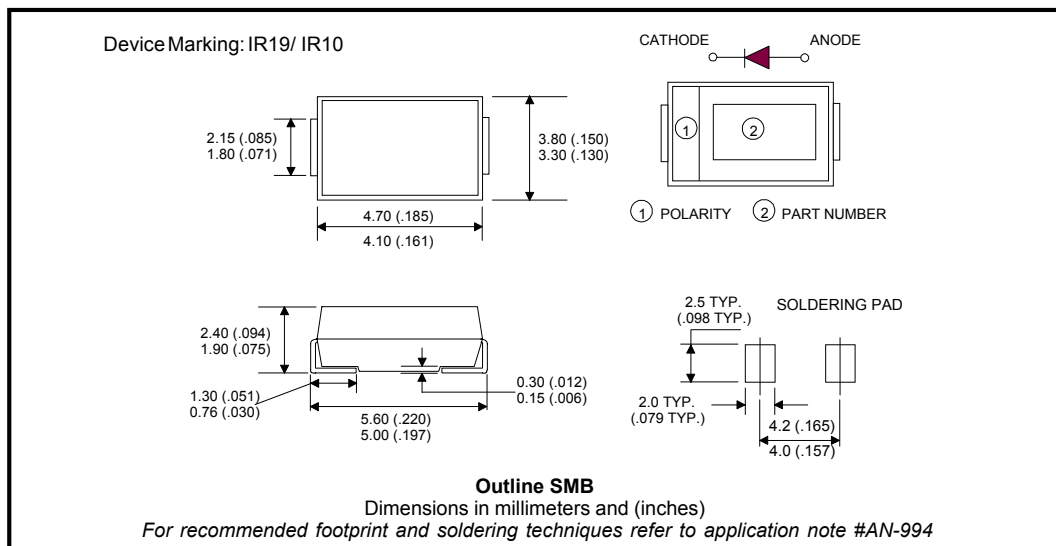
Major Ratings and Characteristics

Characteristics	MBR190TR MBR1100TR	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	90 - 100	V
I_{FSM} @tp = 5 μ s sine	870	A
V_F @1.0 Apk, $T_J=125^\circ\text{C}$	0.63	V
T_J range	-55 to 175	$^\circ\text{C}$

Description/Features

The MBR190TR, MBR1100TR surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



MBRS190TR, MBRS1100TR

Bulletin PD-20592 rev. C 05/02



Voltage Ratings

Part number	MBRS190TR	MBRS1100TR
V _R Max. DC Reverse Voltage (V)	90	100
V _{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	Value	Units	Conditions
I _{F(AV)} Max. Average Forward Current	1.0	A	50% duty cycle @ T _L = 147 °C, rectangular wave form
I _{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	870	A	Following any rated load condition and with rated V _{RWM} applied
	50		
E _{AS} Non-Repetitive Avalanche Energy	5.0	mJ	T _J = 25 °C, I _{AS} = 0.5A, L = 10mH
I _{AR} Repetitive Avalanche Current	0.2	A	

Electrical Specifications

Parameters	Value	Units	Conditions	
V _{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.78	V	@ 1A	T _J = 25 °C
	0.62	V	@ 1A	T _J = 125 °C
I _{RM} Max. Reverse Leakage Current (1) * See Fig. 2	0.5	mA	T _J = 25 °C	V _R = rated V _R
	1.0	mA	T _J = 125 °C	
C _T Typical Junction Capacitance	42	pF	V _R = 5V _{DC} , (test signal range 100kHz to 1MHz) 25°C	
L _S Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body	
dv/dt Max. Volatge Rate of Charge (Rated V _R)	10000	V/ µs		

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T _J Max. Junction Temperature Range (*)	-55 to 175	°C	
T _{stg} Max. Storage Temperature Range	-55 to 175	°C	
R _{thJL} Max. Thermal Resistance Junction to Lead (**)	36	°C/W	DC operation (See Fig. 4)
R _{thJA} Max. Thermal Resistance Junction to Ambient	80	°C/W	DC operation
wt Approximate Weight	0.10(0.003)	g (oz.)	
Case Style	SMB		Similar to DO-214AA
Device Marking	IR19-IR10		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

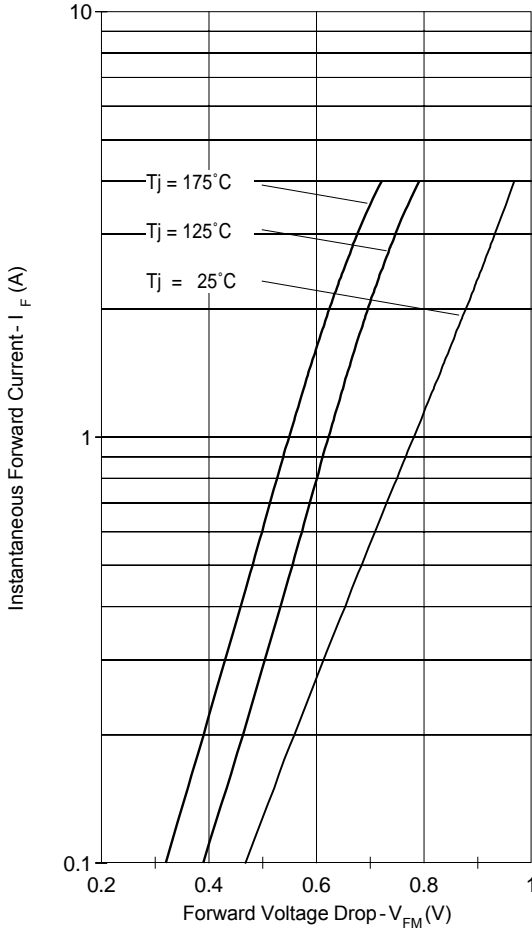


Fig. 1 - Maximum Forward Voltage Drop Characteristics

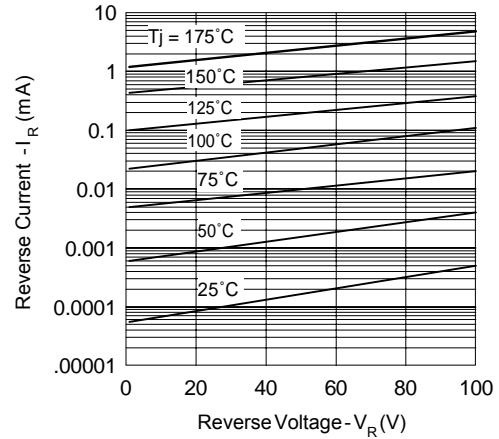


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

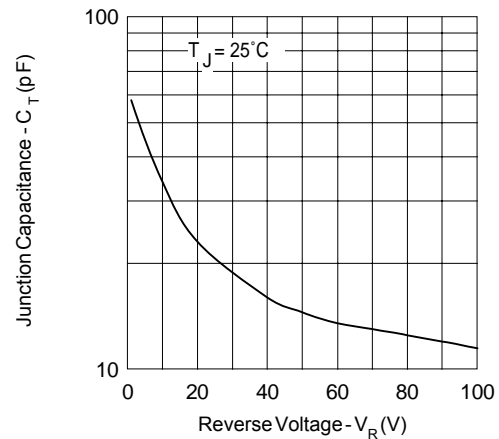


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

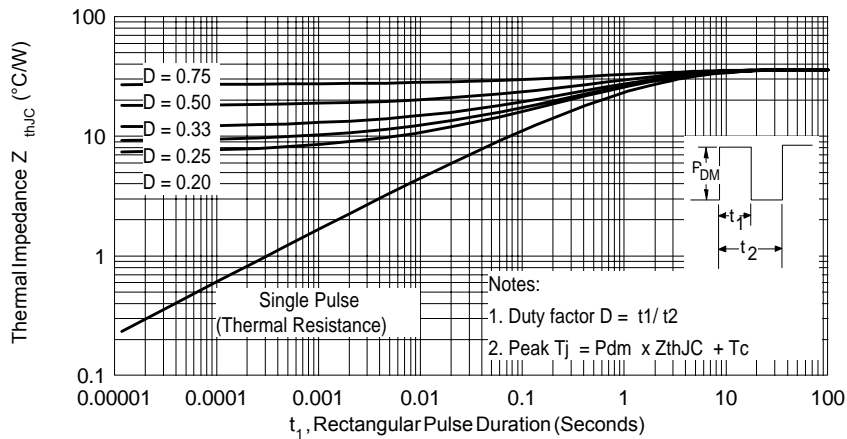


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

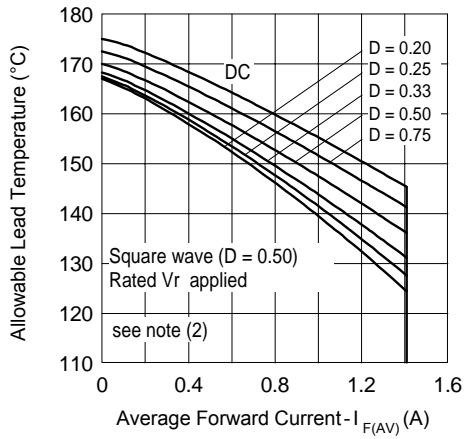


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

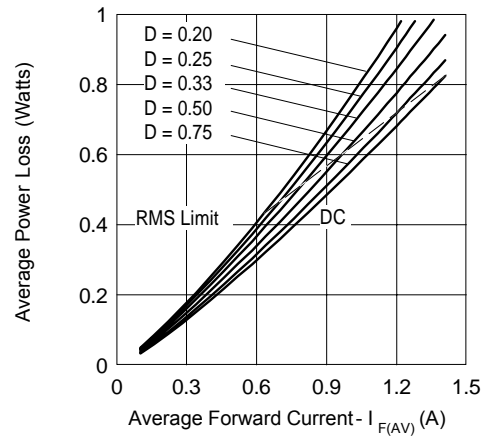


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

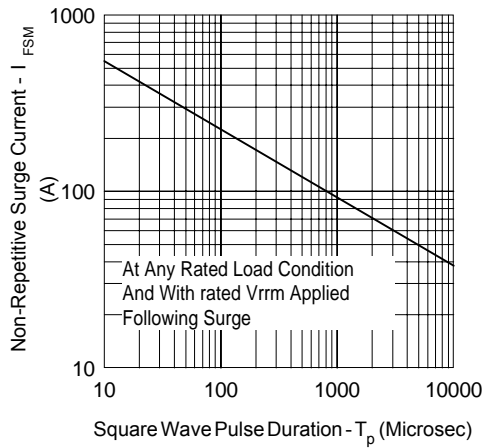
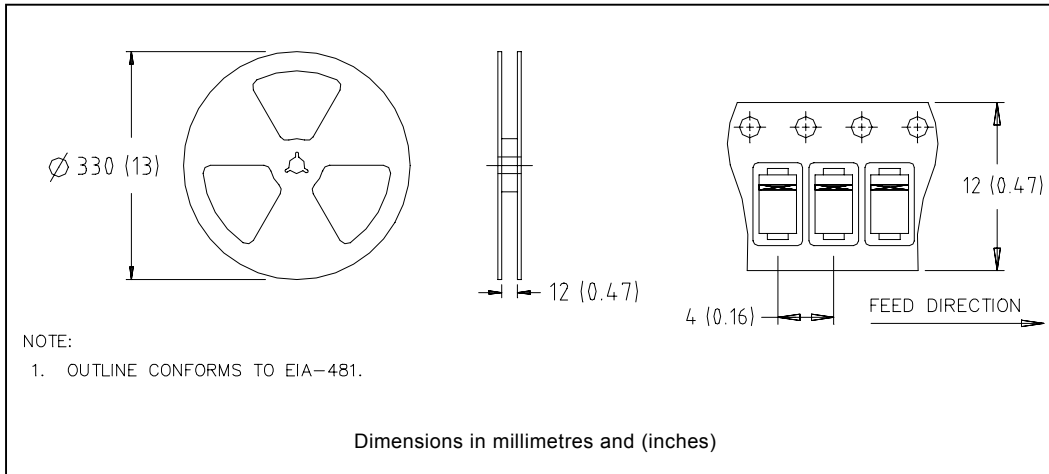


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

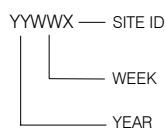
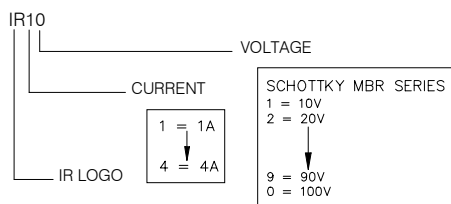
- (2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = 80\% \text{ rated } V_R$

Tape & Reel Information



Marking & Identification

Each device has 2 rows for identification. The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", and the Part Number (indicates the current and the voltage rating). The second row indicates the year, the week of manufacturing and the Site ID.



Ordering Information

MBRS1100TR - TAPE AND REEL

WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 3000 PIECES).

EXAMPLE: MBRS1100TR - 6000 PIECES

MBRS190TR, MBRS1100TR
Bulletin PD-20592 rev. C 05/02

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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TAC Fax: (310) 252-7309
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